

**SENSITRON**  
**SEMICONDUCTOR**

TECHNICAL DATA  
DATA SHEET 697, REV. -

**HERMETIC POWER SCHOTTKY RECTIFIER**  
**200°C Maximum Operation Temperature**

(AVAILABLE SCREENED TO JAN S LEVEL (SS-100); ADD SUFFIX "SS" TO PART NUMBER)

**DESCRIPTION:** A 200 VOLT, 120 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC SHD-3/3A PACKAGE.

**MAXIMUM RATINGS**

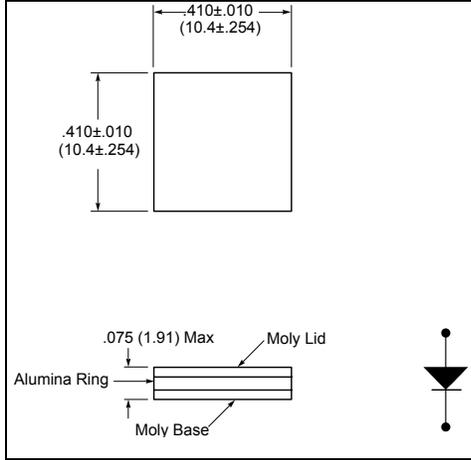
ALL RATINGS ARE @  $T_c = 25^\circ\text{C}$  UNLESS OTHERWISE SPECIFIED.

RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	200	Volts
MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ $T_c=100^\circ\text{C}$ )	$I_o$	120	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT (t=10ms, Sine)	$I_{FSM}$	1650	Amps
MAXIMUM JUNCTION CAPACITANCE ( $V_r=5\text{V}$ )	$C_T$	1800	pF
MAXIMUM THERMAL RESISTANCE (Junction to Mounting Surface, Cathode)	$R_{\theta JC}$	0.20	$^\circ\text{C/W}$
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE	Top/Tstg	-65 to +200	$^\circ\text{C}$

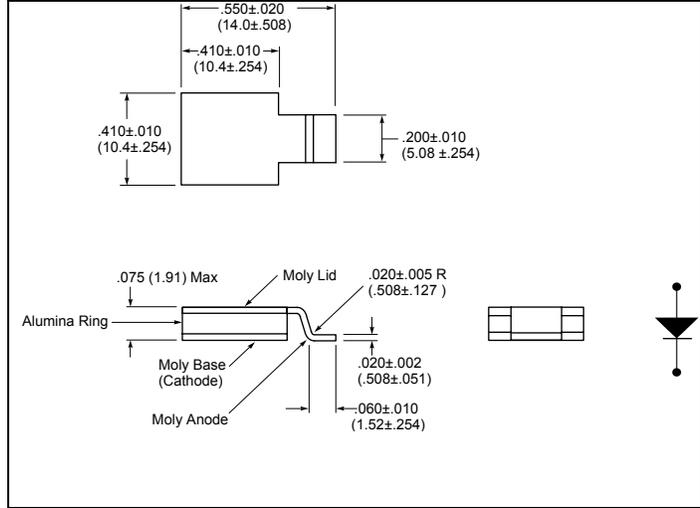
**ELECTRICAL CHARACTERISTICS**

CHARACTERISTIC			
MAXIMUM FORWARD VOLTAGE DROP, Pulsed ( $I_f = 120$ Amps)	$V_f$	$T_J = 25^\circ\text{C}$	Volts
		$T_J = 125^\circ\text{C}$	
MAXIMUM REVERSE CURRENT ( $I_r @ 200$ V PIV)	$I_r$	$T_J = 25^\circ\text{C}$	mA
		$T_J = 125^\circ\text{C}$	

MECHANICAL DIMENSIONS: In Inches / mm

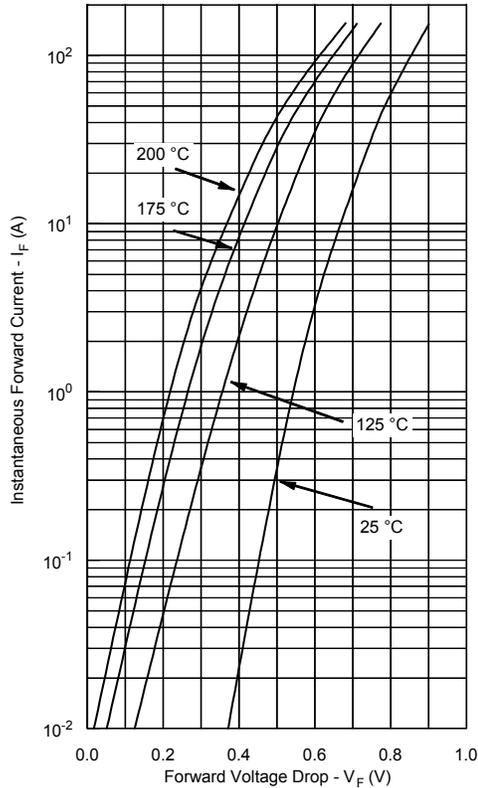


SHD-3

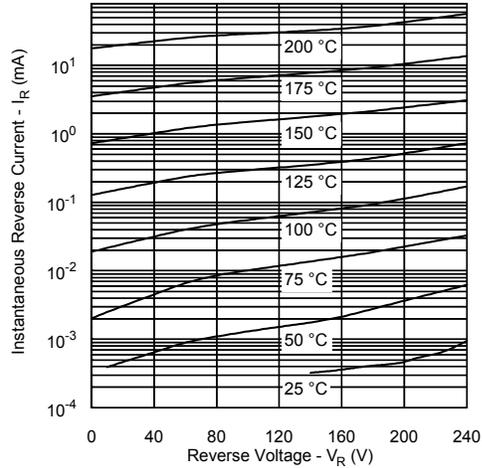


SHD-3A

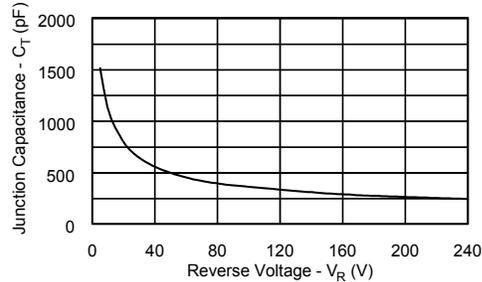
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance



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